

Description

The ST0361D4 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive high-speed data lines. The ST0361D4 complies with the IEC 61000-4-2 (ESD) standard with $\pm 15 \mathrm{kV}$ air and $\pm 8 \mathrm{kV}$ contact discharge. It is assembled into an ultra-small $1.0 \mathrm{x} 0.6 \mathrm{x} 0.5 \mathrm{mm}$ lead-free DFN package. The small size, ultra-low capacitance and high ESD surge protection make ST0361D4 an ideal choice to protect cell phone, digital video interfaces.

Mechanical Characteristics

• Package: DFN1006-2

♦ Lead Finish: NiPdAu

Case Material: "Green" Molding Compound.

♦ UL Flammability Classification Rating 94V-0

Moisture Sensitivity: Level 3 per J-STD-020

Terminal Connections: See Diagram Below

Marking Information: See Below

Features

♦ Ultra small package: 1.0x0.6x0.5mm

♦ Low leakage: nA level

Low operating voltage: 3.3V

Low clamping voltage

2-pin leadless package

Complies with following standards:

- IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV Contact discharge: ±30kV

- IEC61000-4-4 (EFT) 40A (5/50ns)

- IEC61000-4-5 (Lightning) 7A (8/20µs)

RoHS Compliant

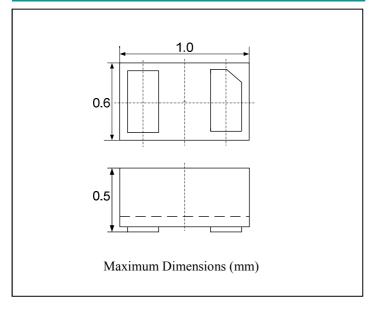
Applications

- Personal Digital Assistants
- Peripherals
- Audio Players
- Notebooks and Handhelds
- ♦ Portable Instrumentation
- Keypads, Side Keys, LCD Displays

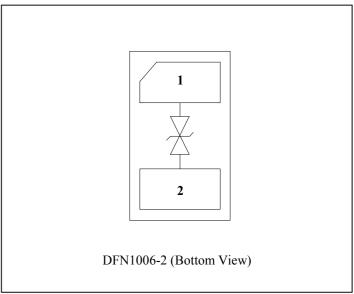
Ordering Information

Part Number	Packaging	Reel Size	
ST0361D4	10000/Tape & Reel	7 inch	

Dimensions



Schematic and PIN Configuration





Absolute Maximum Ratings (TA=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	
Peak Pulse Power (8/20µs)	Ppk	100	W	
Peak Pulse Current (8/20µs)	IPP	10	А	
ESD per IEC 61000-4-2 (Air)	\/===	±30	1.37	
ESD per IEC 61000-4-2 (Contact)	VESD	±30	kV	
Operating Temperature Range	TJ	-45 to + 85	°C	
Storage Temperature Range	Tstg	−55 to +150	°C	

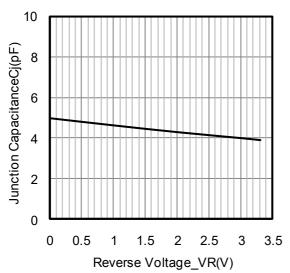
Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			3.3	V	
Snap-Back Voltage	VSB	2.8			V	IT = 50mA
Reverse Leakage Current	I_R			0.5	uA	VRWM = 3.3V
Clamping Voltage	Vc			5	V	IPP = 1A (8 x 20μs pulse)
Clamping Voltage	VC			10	V	IPP = 7A (8 x 20μs pulse)
Junction Capacitance	Сл		5	7	pF	VR = 0V, f = 1MHz

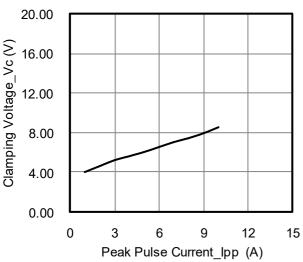
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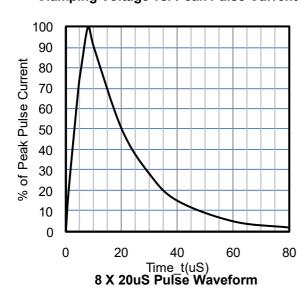
Typical Performance Characteristics (TA=25°C unlessotherwise specified)

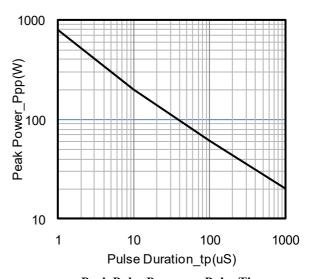


Junction Capacitance vs. Reverse Voltage

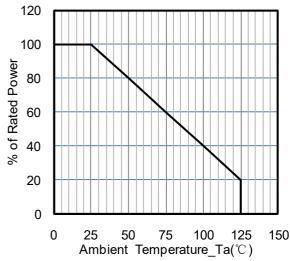


Clamping Voltage vs. Peak Pulse Current

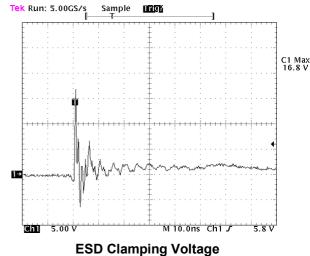




Peak Pulse Power vs. Pulse Time



Power Derating Curve



8 kV Contact per IEC61000-4-2



Applications Information

Device Connection Options

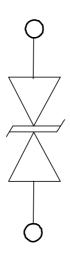
These low capacitance TVS diodes are designed to provide common mode protection for one high-speed line or differential protect tion for one line pair. The device is bidirectional and may be used on lines where the signal polarity is positive and negative.

Circuit Board Layout Recommendations for Suppression of ESD

Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

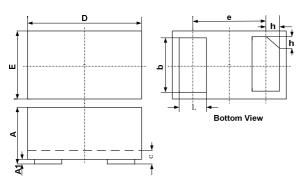
- Place the TVS near the input terminals or connectors to restrict transient coupling.
- Minimize the path length between the TVS and the protected line.
- Minimize all conductive loops including power and ground loops.
- The ESD transient return path to ground should be kept as short as possible.
- Never run critical signals near board edges.
- Use ground planes whenever possible.

Equivalent Circuit Diagram



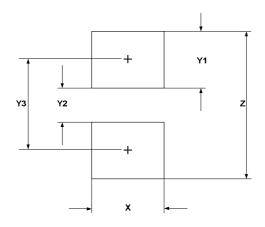


DFN1006-2 Package Outline Drawing



	DIMENSIONS					
07/7.5	MILLIMETERS			INCHES		
SYM	MIN	NOM	MAX	MIN	NOM	MAX
A	0.45	0.50	0.55	0.018	0.020	0.022
A1	0.00	0.02	0.05	0.000	0.001	0.002
b	0.45	0.50	0.55	0.018	0.020	0.022
c	0.12	0.15	0.18	0.005	0.006	0.007
D	0.95	1.00	1.05	0.037	0.039	0.041
e	0.65 BSC			0.026 BSC		
Е	0.55	0.60	0.65	0.022	0.024	0.026
L	0.20	0.25	0.30	0.008	0.010	0.012
h	0.07	0.12	0.17	0.003	0.005	0.007

Suggested Land Pattern



SYM	DIMENSIONS			
	MILLIMETERS	INCHES		
X	0.60	0.024		
Y1	0.50	0.020		
Y2	0.30	0.012		
Y3	0.80	0.032		
Z	1.30	0.052		

Contact Information

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